



Tentative Data

# Insulated Gate Bi-Polar Transistor

## Type T1500EC33E

### Absolute Maximum Ratings

	<b>VOLTAGE RATINGS</b>	<b>MAXIMUM LIMITS</b>	<b>UNITS</b>
$V_{CES}$	Collector – emitter voltage	3300	V
$V_{DC\ link}$	Permanent DC voltage for 100 FIT failure rate.	1800	V
$V_{GES}$	Peak gate – emitter voltage	$\pm 20$	V

	<b>RATINGS</b>	<b>MAXIMUM LIMITS</b>	<b>UNITS</b>
$I_C$	Continuous DC collector current, IGBT	1500	A
$I_{CRM}$	Repetitive peak collector current, $t_p=1ms$ , IGBT	3000	A
$I_{ECO}$	Maximum reverse emitter current, $t_p=100\mu s$ , (note 2 & 3)	3000	A
$P_{MAX}$	Maximum power dissipation, IGBT (note 2)	9.6	kW
$T_{j\ op}$	Operating temperature range	-40 to +125	$^{\circ}C$
$T_{stg}$	Storage temperature range	-40 to +125	$^{\circ}C$

Notes: -

- 1) Unless otherwise indicated  $T_j = 125^{\circ}C$ .
- 2)  $T_{sink} = 25^{\circ}C$ , double side cooled.
- 3) Maximum commutation loop inductance 300nH.

## Characteristics

### IGBT Characteristics

	PARAMETER	MIN	TYP	MAX	TEST CONDITIONS	UNITS
V <sub>CE(sat)</sub>	Collector – emitter saturation voltage	-	2.57	2.97	I <sub>C</sub> = 1500A, V <sub>GE</sub> = 15V, T <sub>j</sub> = 25°C	V
		-	3.40	3.80	I <sub>C</sub> = 1500A, V <sub>GE</sub> = 15V	V
V <sub>0</sub>	Threshold voltage	-	-	1.79	Current range: 500A – 1500A	V
r <sub>s</sub>	Slope resistance	-	-	1.34		mΩ
V <sub>GE(TH)</sub>	Gate threshold voltage	-	5.3	-	V <sub>CE</sub> = V <sub>GE</sub> , I <sub>C</sub> = 125mA	V
I <sub>CES</sub>	Collector – emitter cut-off current	-	13	40	V <sub>CE</sub> = V <sub>CES</sub> , V <sub>GE</sub> = 0V	mA
I <sub>GES</sub>	Gate leakage current	-	-	±15	V <sub>GE</sub> = ±20V	μA
C <sub>ies</sub>	Input capacitance	-	200	-	V <sub>CE</sub> = 25V, V <sub>GE</sub> = 0V, f = 1MHz	nF
t <sub>d(on)</sub>	Turn-on delay time	-	1.7	-	I <sub>C</sub> = 1500A, V <sub>CE</sub> = 1800V, di/dt = 2700A/μs	μs
t <sub>r(V)</sub>	Rise time	-	1.6	-		μs
Q <sub>g(on)</sub>	Turn-on gate charge	-	25	-	V <sub>GE</sub> = ±15V, L <sub>s</sub> = 320μH	μC
E <sub>on</sub>	Turn-on energy	-	3.9	-	R <sub>G(ON)</sub> = 1.5Ω, R <sub>G(OFF)</sub> = 10Ω, C <sub>GE</sub> = TBC	J
t <sub>d(off)</sub>	Turn-off delay time	-	5.3	-	Freewheel diode type E1500MC33E at T <sub>j</sub> = 125°C	μs
t <sub>f(l)</sub>	Fall time	-	1.5	-		μs
Q <sub>g(off)</sub>	Turn-off gate charge	-	20	-	(Notes 3, 4 & 5)	μC
E <sub>off</sub>	Turn-off energy	-	4.1	-		J
I <sub>sc</sub>	Short circuit current	-	4500	-	V <sub>GE</sub> = +15V, V <sub>CC</sub> = 1800V, V <sub>CEmax</sub> ≤ V <sub>CES</sub> , t <sub>p</sub> ≤ 10μs	A

### Thermal Characteristics

	PARAMETER	MIN	TYP	MAX	TEST CONDITIONS	UNITS
R <sub>thJK</sub>	Thermal resistance junction to sink, IGBT	-	-	10.4	Double side cooled	K/kW
		-	-	17	Collector side cooled	K/kW
		-	-	26.9	Emitter side cooled	K/kW
F	Mounting force	25	-	35	Note 2	kN
W <sub>t</sub>	Weight	-	1.2	-		kg

#### Notes:-

- 1) Unless otherwise indicated T<sub>j</sub> = 125°C.
- 2) Consult application note 2008AN01 for detailed mounting requirements.
- 3) C<sub>GE</sub> is additional gate - emitter capacitance added to output of gate drive circuit.
- 4) E<sub>on</sub> integration time 15μs from 10% rising I<sub>G</sub>.
- 5) E<sub>off</sub> integration time 15μs from 90% falling V<sub>GE</sub>.

**Curves**

Figure 1 – Typical collector-emitter saturation voltage characteristics

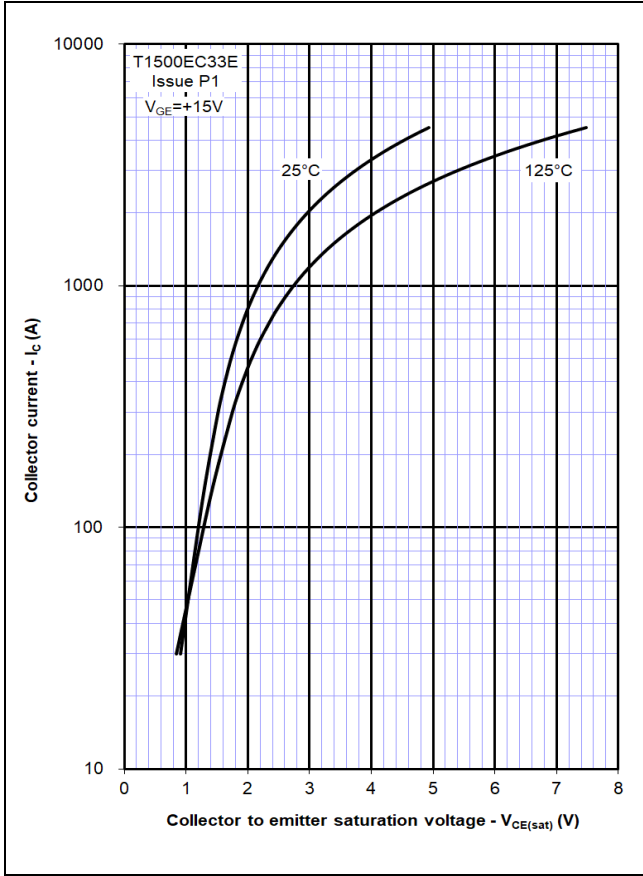


Figure 2 – Typical output characteristic

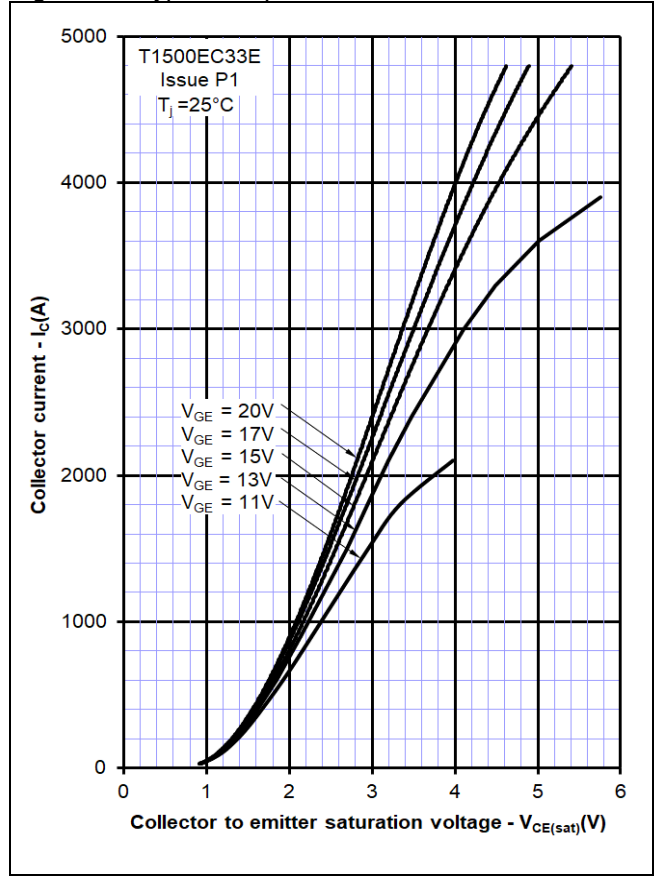


Figure 3 – Typical output characteristic

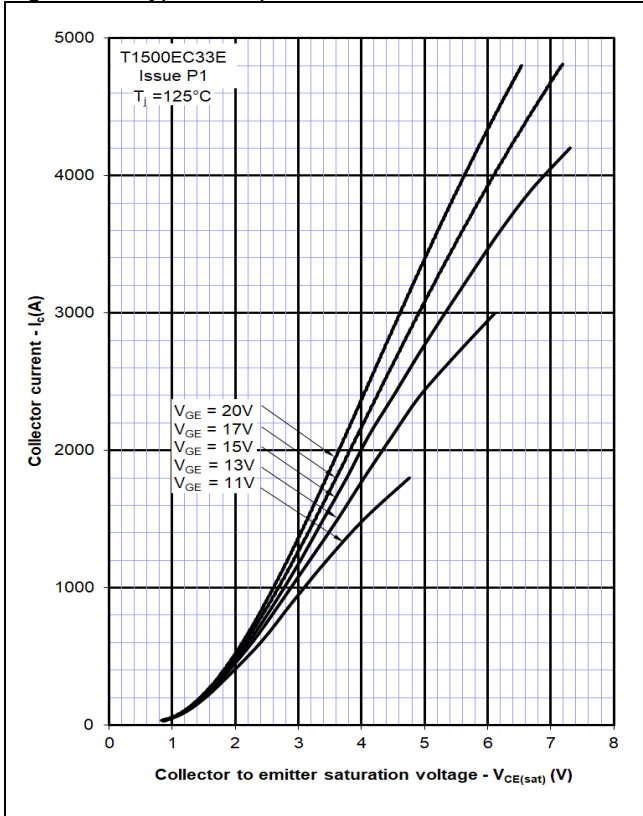


Figure 4 – Typical turn-on delay time vs gate resistance

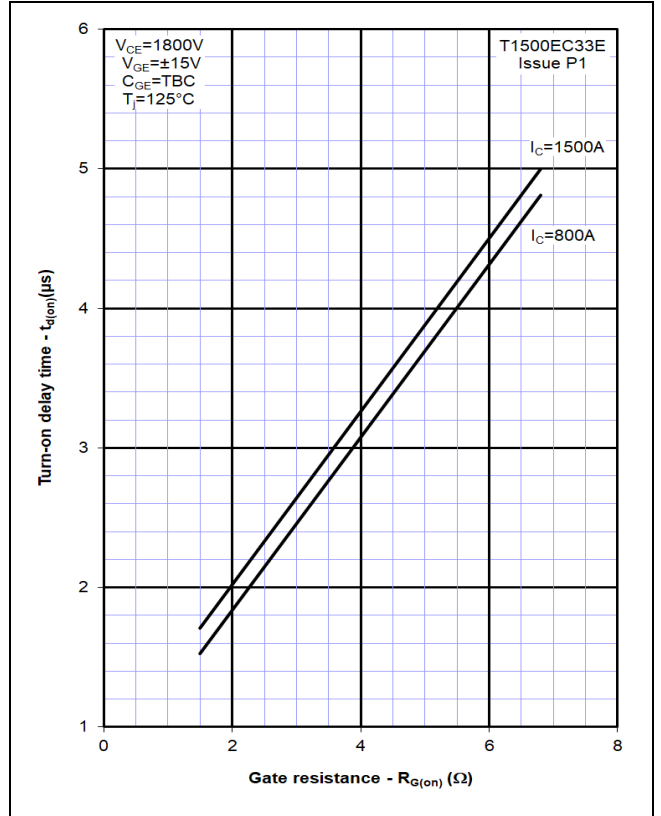


Figure 5 – Typical turn-off delay time vs. gate resistance

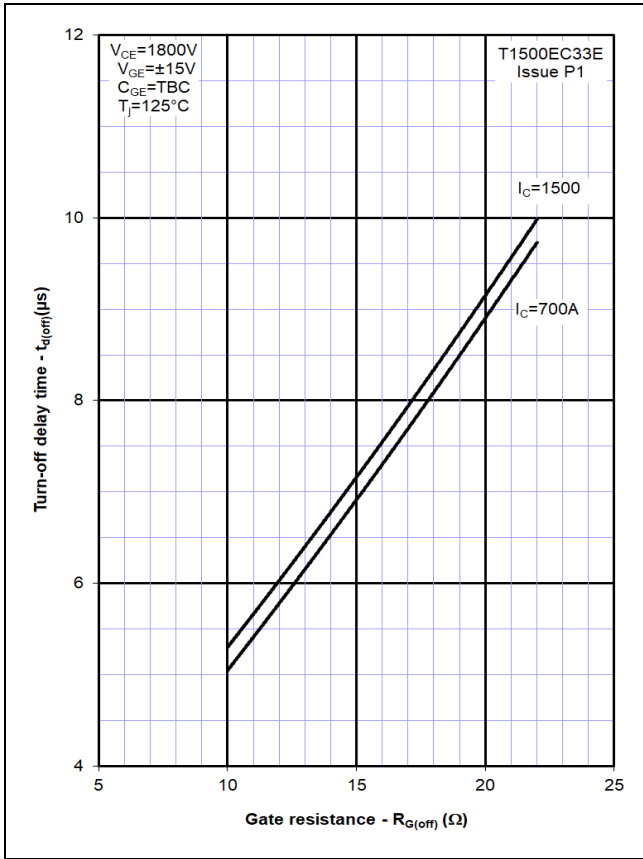


Figure 6 – Typical turn-on energy vs. collector current

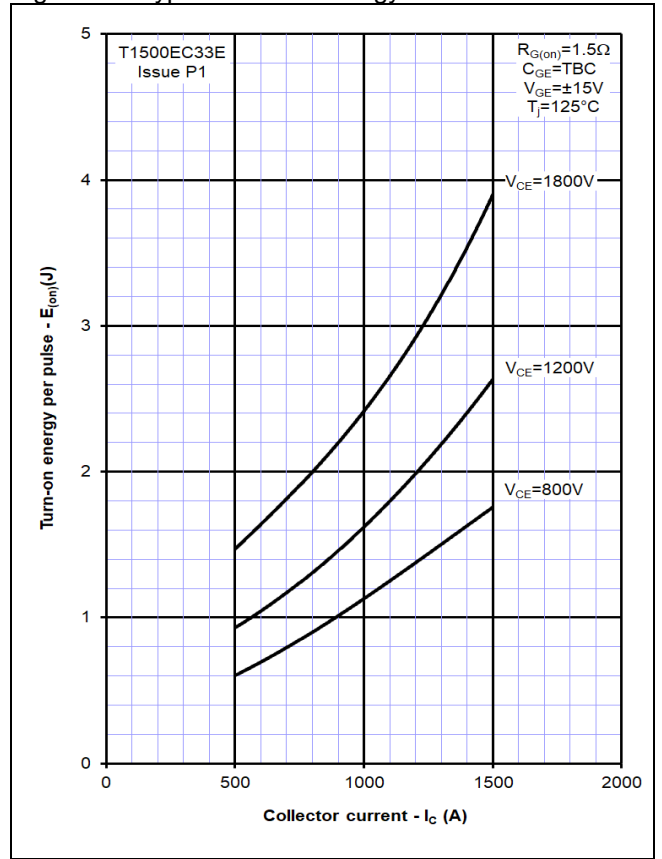


Figure 7 – Typical turn-on energy vs. di/dt

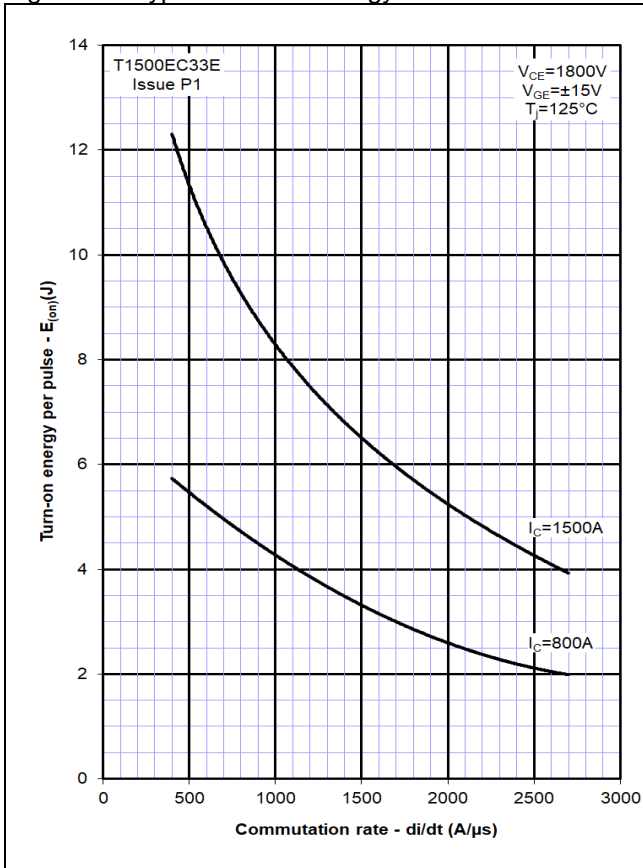


Figure 8 – Typical turn-off energy vs. collector current

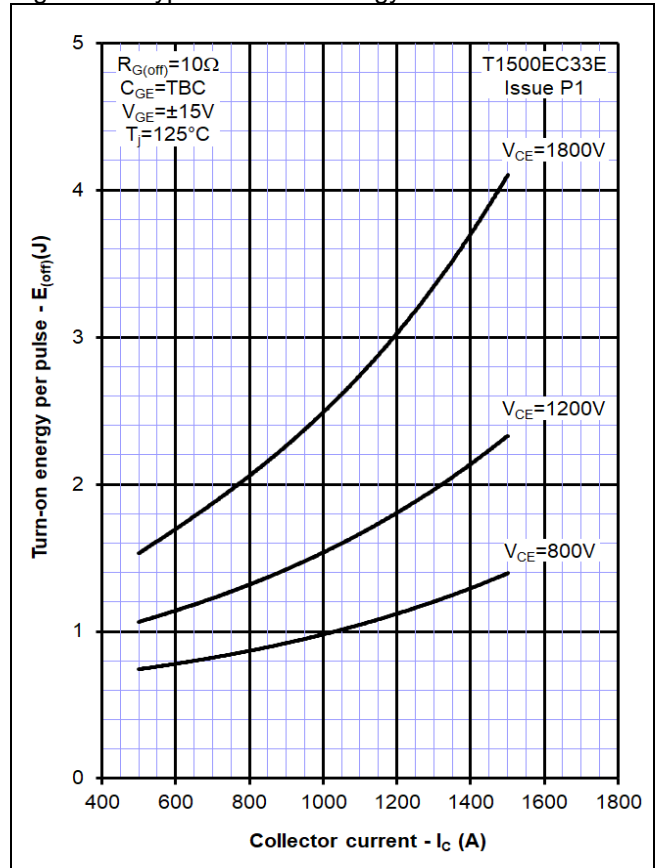


Figure 9 – Turn-off energy vs voltage

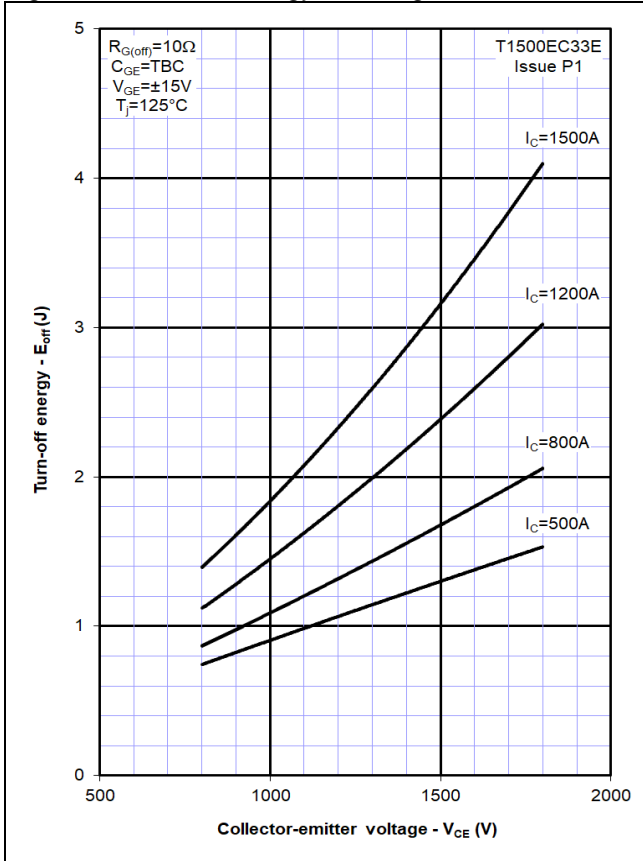


Figure 10 – Safe operating area

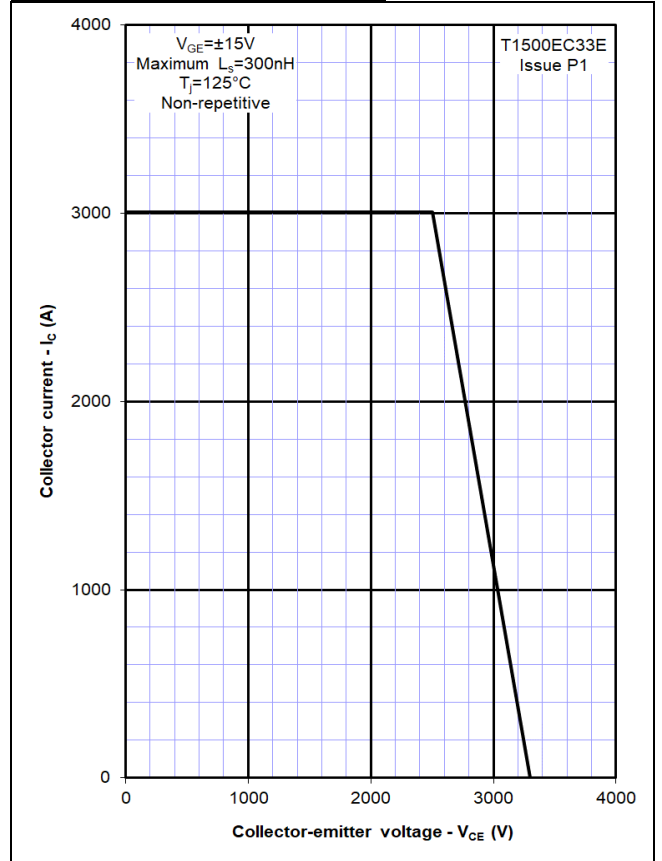
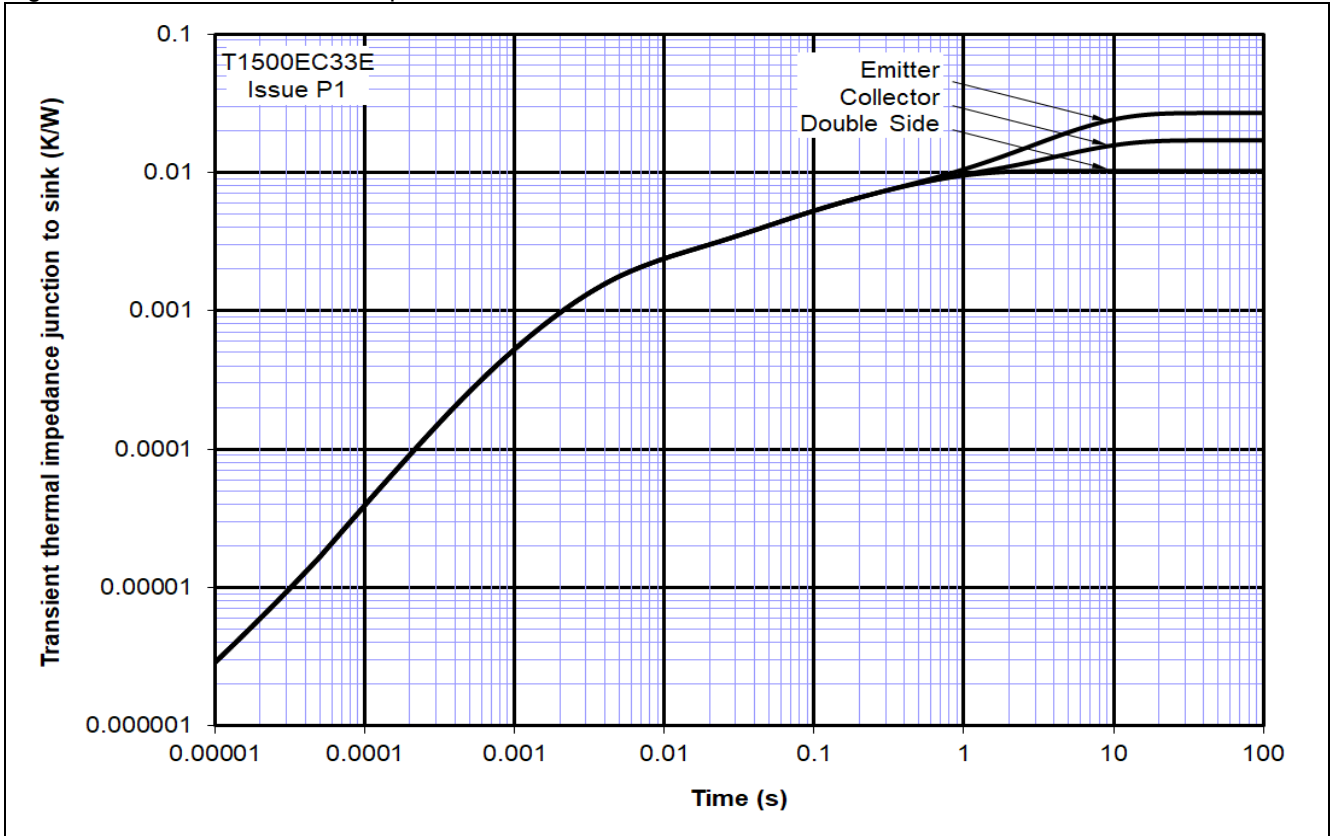
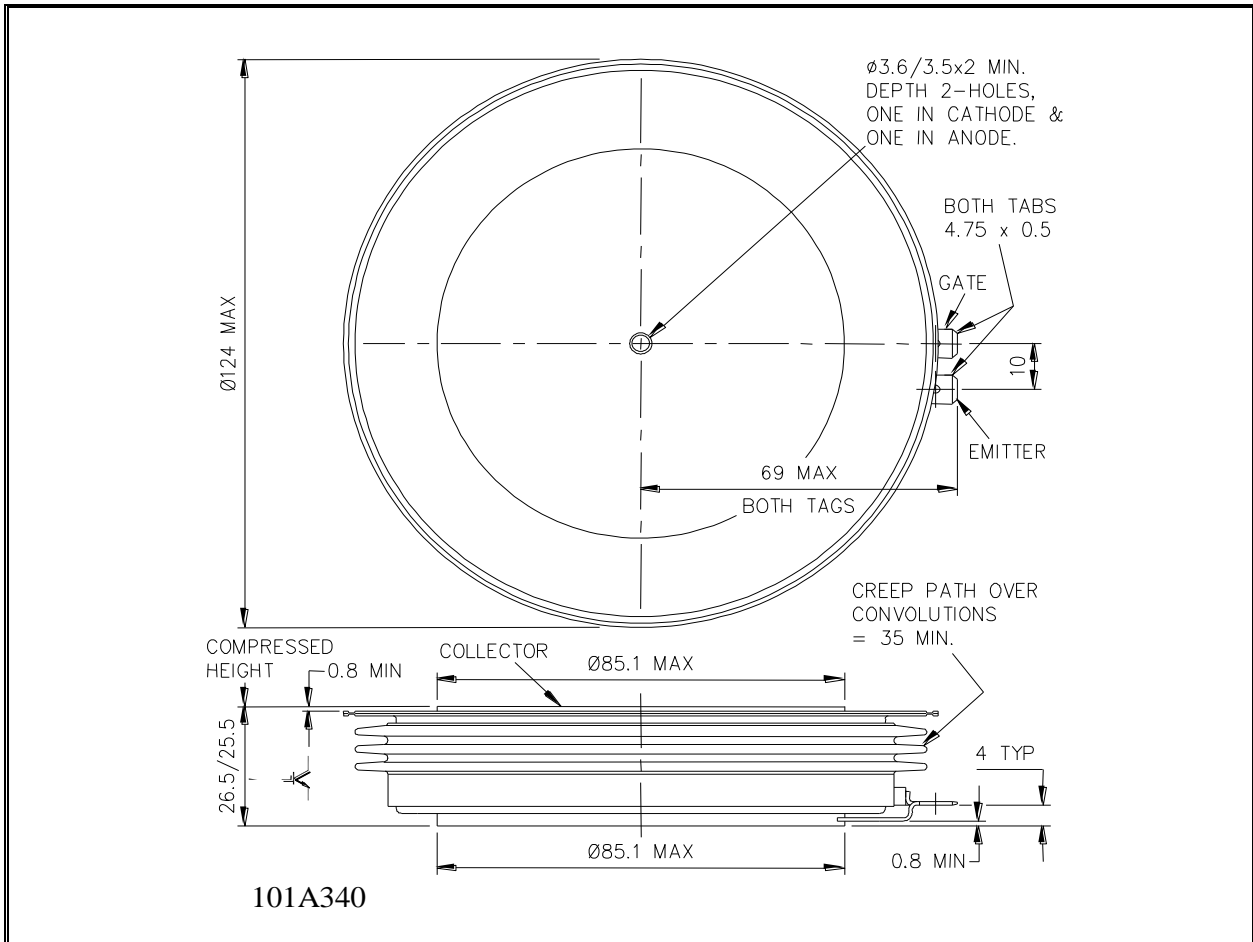


Figure 11 – Transient thermal impedance



## Outline Drawing & Ordering Information



### ORDERING INFORMATION

(Please quote 10 digit code as below)

T1500	EC	33	E
Fixed type Code	Fixed Outline Code	Voltage Grade $V_{CES}/100$ 33	Fixed format code

 Typical order code: T1500EC33E ( $V_{CES} = 3300V$ )

**IXYS Semiconductor GmbH**  
 Edisonstraße 15  
 D-68623 Lampertheim  
 Tel: +49 6206 503-0  
 Fax: +49 6206 503-627  
 E-mail: [marcom@ixys.de](mailto:marcom@ixys.de)



**IXYS**  
 A Littelfuse Technology

**IXYS UK Westcode Ltd**  
 Langley Park Way, Langley Park,  
 Chippenham, Wiltshire, SN15 1GE.  
 Tel: +44 (0)1249 444524  
 E-mail: [sales@ixysuk.com](mailto:sales@ixysuk.com)

**IXYS Corporation**  
 1590 Buckeye Drive  
 Milpitas CA 95035-7418  
 Tel: +1 (408) 457 9000  
 Fax: +1 (408) 496 0670  
 E-mail: [sales@ixys.net](mailto:sales@ixys.net)

[www.littelfuse.com](http://www.littelfuse.com)

[www.ixysuk.com](http://www.ixysuk.com)

[www.ixys.net](http://www.ixys.net)

**IXYS Long Beach**  
 IXYS Long Beach, Inc  
 2500 Mira Mar Ave, Long Beach  
 CA 90815  
 Tel: +1 (562) 296 6584  
 Fax: +1 (562) 296 6585  
 E-mail: [service@ixyslongbeach.com](mailto:service@ixyslongbeach.com)

The information contained herein is confidential and is protected by Copyright. The information may not be used or disclosed except with the written permission of and in the manner permitted by the proprietors IXYS UK Westcode Ltd.

© IXYS UK Westcode Ltd.

In the interest of product improvement, IXYS UK Westcode Ltd reserves the right to change specifications at any time without prior notice.

Devices with a suffix code (2-letter, 3-letter or letter/digit/letter combination) added to their generic code are not necessarily subject to the conditions and limits contained in this report.

**Disclaimer Notice**

Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at [www.littelfuse.com/disclaimer-electronics](http://www.littelfuse.com/disclaimer-electronics)